

Digital Attenuator, 1-Bit, 15 dB DC-2.0 GHz

**AT-267
V4**

Features

- Single 15-dB Step
- Low Loss, 0.3 dB Typical @ 900 MHz
- 2.5 to 5.0 Volt Operation
- SOT-25 Plastic Package
- Tape and Reel Packaging Available

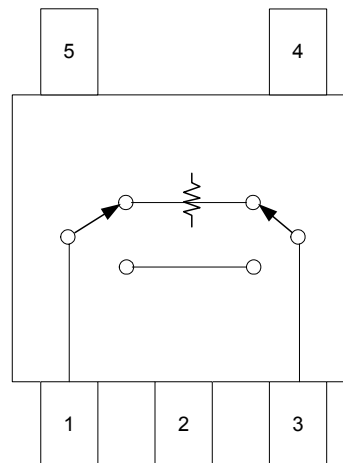
Description

M/A-COM's AT-267 is a 1-bit, 15-dB step GaAs MMIC digital attenuator in a low cost SOT-25, 5 lead surface mount plastic package. The AT-267 is ideally suited for use where high accuracy, very low power consumption and low intermodulation products are required.

Typical applications include wireless handsets, base stations, wireless LAN equipment, GPS receivers and any RF applications with automatic gain/level control circuits.

The AT-267 is fabricated as a monolithic GaAs integrated circuit using a mature PHEMT process. The process features full chip passivation for performance and reliability.

Functional Schematic



Pin Configuration

Pin No.	Function	Pin No.	Function
1	RF1	4	V1
2	Ground	5	V2
3	RF2		

Ordering Information ¹

Part Number	Package
AT-267TR	Tape and Reel (1K Reel)
AT-267TR-3000	Tape and Reel (3K Reel)
AT-267SMB	Sample Board

1. Reference Application Note M513 for reel size information.

Absolute Maximum Ratings ²

Parameter	Absolute Maximum
Input Power	+21 dBm
Control Voltage	$ V_C \leq 8V$
Operating Temperature	-40°C to +85°C
Storage Temperature	-65°C to +150°C

2. Exceeding any one or combination of these limits may cause permanent damage to this device.

**Digital Attenuator, 1-Bit, 15 dB
DC-2.0 GHz**

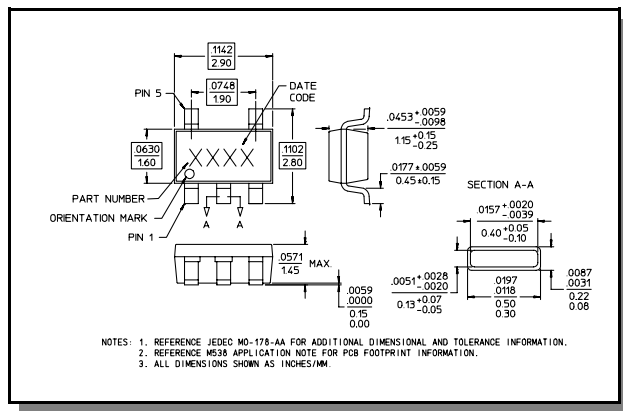
**AT-267
V4**

Electrical Specifications³: $T_A = 25^\circ\text{C}$, $V_C = +2.5\text{ Volts}$, $Z_0 = 50\ \Omega$

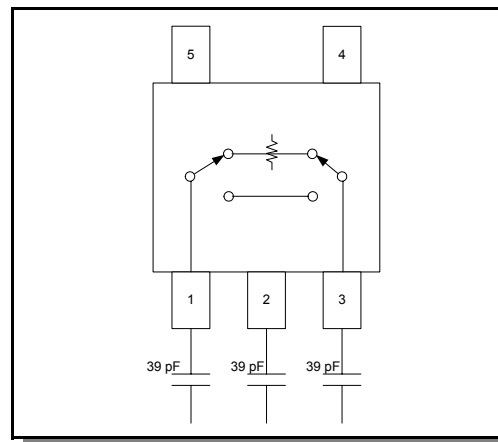
Parameter	Test Conditions	Units	Min	Typ	Max
Insertion Loss (Reference State)	1.0 GHz	dB	—	0.3	0.4
	2.0 GHz		—	0.4	0.5
Attenuation	1.0 GHz	dB	14.6	15.1	15.6
	2.0 GHz	dB	14.4	14.9	15.4
VSWR	1.0 GHz	Ratio	—	1.2:1	—
	2.0 GHz	Ratio	—	1.3:1	—
Input IP_3	1.0 GHz	dBm	40	50	—
	Insertion Loss State Attenuation State	dBm	40	50	—
P_{1dB}	1.0 GHz	dBm	24	26	—
	Insertion Loss State Attenuation State	dBm	20	23	—
Control Current	—	μA	—	—	10
Trise, Tfall	10% to 90% RF, 90% to 10% RF	nS	—	29	—
Ton, Toff	50% Control to 90% RF, 50% Control to 10% RF	nS	—	50	—
Transients	In-band	mV	—	10	—

3. For positive voltage control, external DC blocking capacitors are required on all RF ports (pins 1, 2 and 3).

SOT-25



Positive Control Voltage Schematic



Truth Table^{4,5}

Mode (Control)	V1	V2	Attenuation
Positive ⁴	$0 \pm 0.2\text{V}$	$+2.5\text{V to } +5\text{V}$	15 dB
	$+2.5\text{V to } +5\text{V}$	$0 \pm 0.2\text{V}$	Reference State
Negative ⁵	$0 \pm 0.2\text{V}$	$-2.5\text{V to } -5\text{V}$	Reference State
	$-2.5\text{V to } -5\text{V}$	$0 \pm 0.2\text{V}$	15 dB

4. External DC blocking capacitors are required as noted.

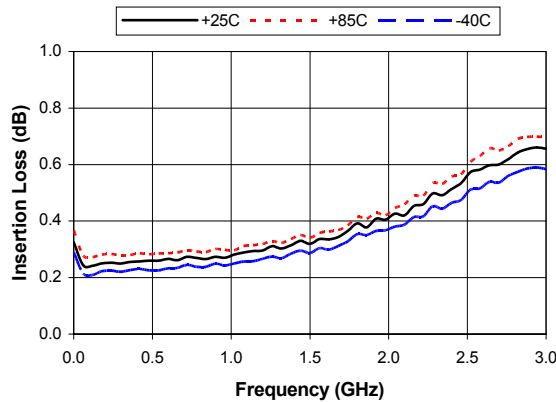
5. If negative control is used, DC blocking capacitors are not required on RF ports and ground.

Digital Attenuator, 1-Bit, 15 dB DC-2.0 GHz

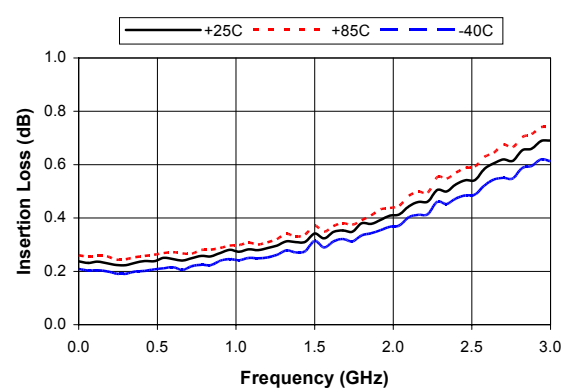
AT-267
V4

Typical Performance Curves

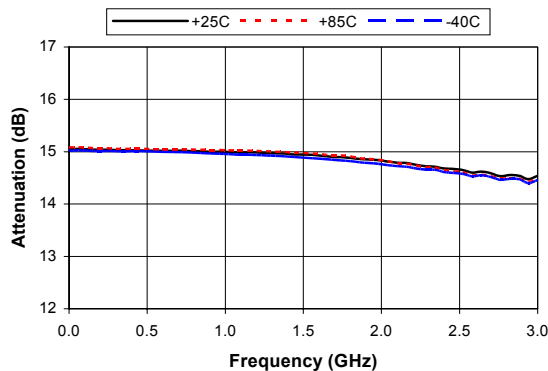
Insertion Loss vs. Frequency over Temperature with Negative Control



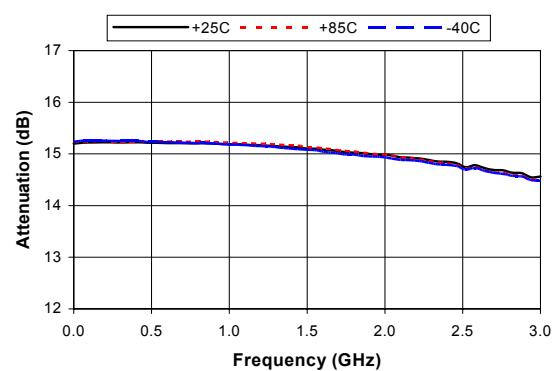
Insertion Loss vs. Frequency over Temperature with Positive Control



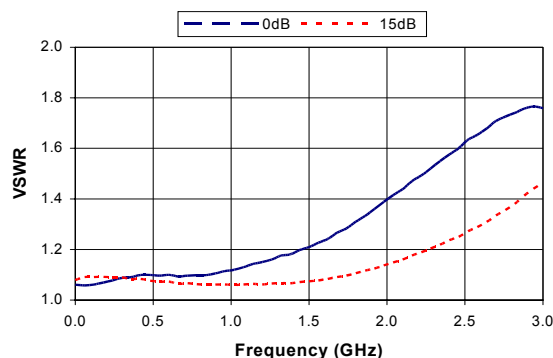
Attenuation vs. Frequency over Temperature with Negative Control



Attenuation vs. Frequency over Temperature with Positive Control



VSWR, 0 and 15 dB States with Negative Control at +25°C



VSWR, 0 and 15 dB States with Positive Control at +25°C

